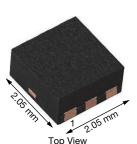
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Vishay Siliconix

P-Channel 20 V (D-S) MOSFET

PowerPAK[®] SC-70-6L Single





Marking code: BL

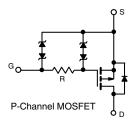
PRODUCT SUMMARY				
V _{DS} (V)	-20			
$R_{DS(on)}$ max. (Ω) at V_{GS} = -4.5 V	0.018			
$R_{DS(on)}$ max. (Ω) at V_{GS} = -2.5 V	0.026			
$R_{DS(on)}$ max. (Ω) at V_{GS} = -1.8 V	0.065			
Q _g typ. (nC)	20			
I _D (A) ^a	12			
Configuration	Single			

FEATURES

- TrenchFET[®] power MOSFET
- New thermally enhanced PowerPAK[®] SC-70 package
 - Small footprint area
 - Low on-resistance
- 100 % R_g tested
- Built in ESD protection with Zener diode
- Typical ESD performance: 1800 V
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Portable devices
 - Load switch
 - Battery switch
 - Charger switch



ORDERING INFORMATION

Package	PowerPAK SC-70
Lead (Pb)-free and halogen-free	SiA433EDJ-T1-GE3

ABSOLUTE MAXIMUM RATINGS	(T _A = 25 °C, unless	s otherwise not	ed)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	-20	V	
Gate-source voltage		V _{GS}	V _{GS} ± 12		
Continuous drain current (T _J = 150 °C)	T _C = 25 °C		-12 ^a		
	T _C = 70 °C		-12 ^a		
	T _A = 25 °C	l _D	-11.3 ^{b, c}		
	T _A = 70 °C		-9.1 ^{b, c}	A	
Pulsed drain current		I _{DM}	-50		
Continuous source-drain diode current	T _C = 25 °C	۱ _S	-12 ^a		
	T _A = 25 °C		-2.9 ^{b, c}		
Maximum power dissipation	T _C = 25 °C	P _D	19		
	T _C = 70 °C		12	w	
	T _A = 25 °C		3.5 ^{b, c}	vv	
	T _A = 70 °C		2.2 ^{b, c}		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +150	°C	
Soldering recommendations (peak temperature) d, e			260		

THERMAL RESISTANCE RATINGS PARAMETER SYMBOL TYPICAL MAXIMUM UNIT Maximum junction-to-ambient b, f t ≤ 5 s **R**_{thJA} 28 36 °C/W Maximum junction-to-case (drain) Steady state R_{thJC} 5.3 6.5

Notes

a. Package limited

b. Surface mounted on 1" x 1" FR4 board

c. t = 5 s

e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components

f. Maximum under steady state conditions is 80 °C/W

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RoHS COMPLIANT HALOGEN FREE

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d. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

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SiA433EDJ

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PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static				•		
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 V, I_D = -250 \mu A$	-20	-	-	V
V _{DS} temperature coefficient	$\Delta V_{DS}/T_{J}$		-	-12	-	mV/°C
V _{GS(th)} temperature coefficient	$\Delta V_{GS(th)}/T_J$	I _D = -250 μA	-	3	-	
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	-0.5	-	-1.2	V
Gate-source leakage		$V_{DS} = 0 V, V_{GS} = \pm 12 V$	-	-	± 20	
	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 4.5 V	-	-	± 0.5	
Zero gate voltage drain current		$V_{DS} = -20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	-	-	-1	μA
	I _{DSS}	V_{DS} = -20 V, V_{GS} = 0 V, T_{J} = 55 $^{\circ}\text{C}$	-	-	-10	
On-state drain current ^a	I _{D(on)}	$V_{DS} \leq$ -5 V, V_{GS} = -4.5 V	-20	-	-	А
Drain-source on-state resistance ^a		V_{GS} = -4.5 V, I _D = -7.6 A	-	0.015	0.018	Ω
	R _{DS(on)}	V_{GS} = -2.5 V, I _D = -6.3 A	-	0.021	0.026	
		V_{GS} = -1.8 V, I _D = -2.5 A	-	0.040	0.065	
Forward transconductance a	9 _{fs}	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -7.6 \text{ A}$	-	35	-	S
Dynamic ^b						
Total gate charge	0	$V_{DS} = -10$ V, $V_{GS} = -8$ V, $I_D = -11$ A $V_{DS} = -10$ V, $V_{GS} = -4.5$ V, $I_D = -11$ A	-	50	75	nC
Gate-source charge	Qg		-	20	30	
	Q _{gs}		-	3.3	-	
Gate-drain charge	Q _{gd}		-	8.4	-	
Gate resistance	R _g	f = 1 MHz	200	1000	2000	Ω
Turn-on delay time	t _{d(on)}		-	0.71	1.1	
Rise time	tr	V_{DD} = -10 V, R_L = 1 Ω	-	1.7	2.6	
Turn-off delay time	t _{d(off)}	$I_D \cong -9$ Å, $V_{GEN} = -4.5$ V, $R_g = 1 \Omega$	-	6	9	
Fall time	t _f		-	3.2	5	μs
Turn-on delay time	t _{d(on)}		-	0.3	0.45	μο
Rise time	t _r	V_{DD} = -10 V, R _L = 1 Ω I _D \cong -9 A, V _{GEN} = -10 V, R _g = 1 Ω	-	0.6	0.9	
Turn-off delay time	t _{d(off)}		-	10	15	
Fall time	t _f		-	3.5	5.5	
Drain-Source Body Diode Characteris	stics					
Continuous source-drain diode current	۱ _S	T _C = 25 °C -	-	-12	A	
Pulse diode forward current	I _{SM}		-	-	-50	
Body diode voltage	V _{SD}	$I_{\rm S} = -9$ A, $V_{\rm GS} = 0$ V	-	-0.85	-1.2	V
Body diode reverse recovery rime	t _{rr}	I _F = 9 A, di/dt =100 A/μs,	-	30	60	ns
Body diode reverse recovery charge	Q _{rr}		-	20	40	nC
Reverse recovery fall time	t _a	T _J =25 °C	-	13	-	
Reverse recovery rise time	t _b		-	17	-	ns

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

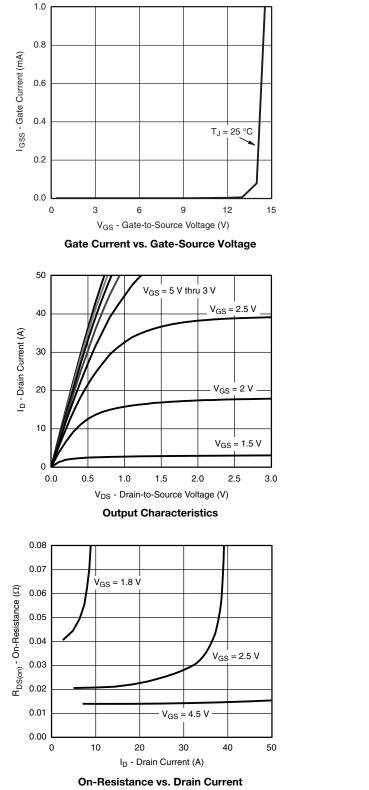
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

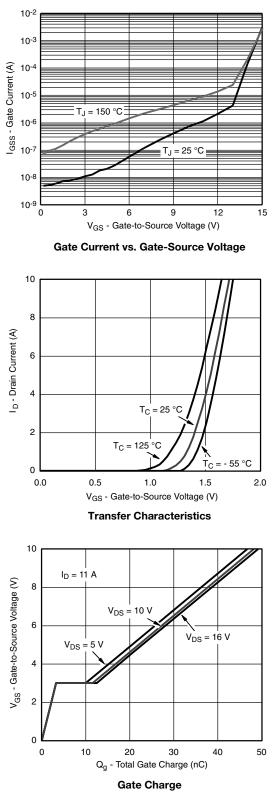
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





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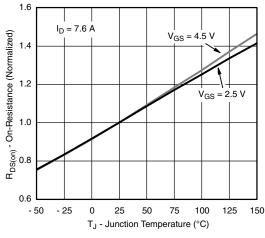
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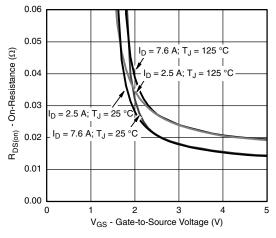


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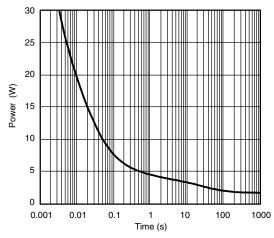
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



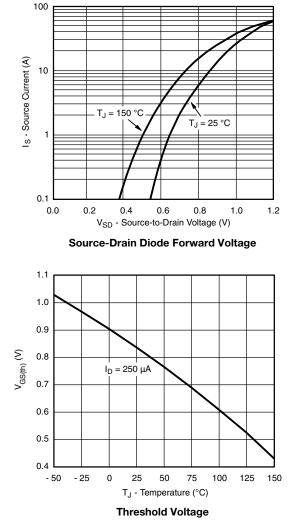
On-Resistance vs. Junction Temperature

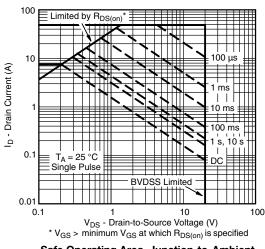


On-Resistance vs. Gate-to-Source Voltage



Single Pulse Power, Junction-to-Ambient





Safe Operating Area, Junction-to-Ambient

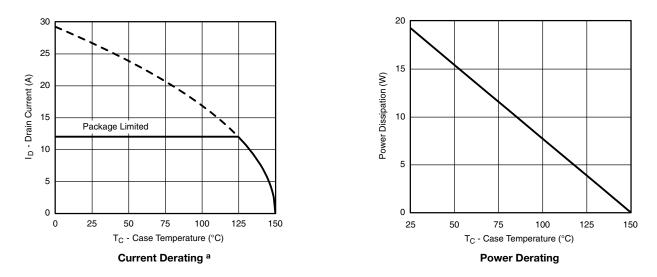
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



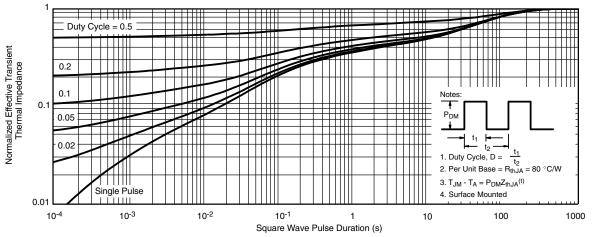
Note

a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit

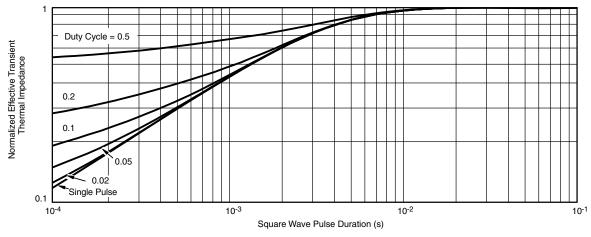


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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

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PowerPAK[®] SC70-6L

VISHA

b PIN2 PIN1 PIN3 _ ₹



b

PIN3

__ ₿

PIN2

PIN1

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RECOMMENDED PAD LAYOUT FOR PowerPAK[®] SC70-6L Single



Dimensions in mm/(Inches)

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